

## LEAD-FREE / RoHS-COMPLIANT HIGH POWER BIAS TEE

**BTN1-0026**

The BTN1-0026 is constructed using a custom-made, resonance-free conical inductor to achieve extremely broadband performance. By minimizing the overall inductor size and using proprietary packaging techniques, the BTN1-0026 is a superior option in terms of performance, reliability and ease-of-use when compared to cumbersome user-designed bias tees employing off-the-shelf conical inductors. The extremely low cutoff and resonance free operation makes the BTN1-0026 suitable for biasing amplifiers, lasers, and modulators driven with high frequency data patterns.



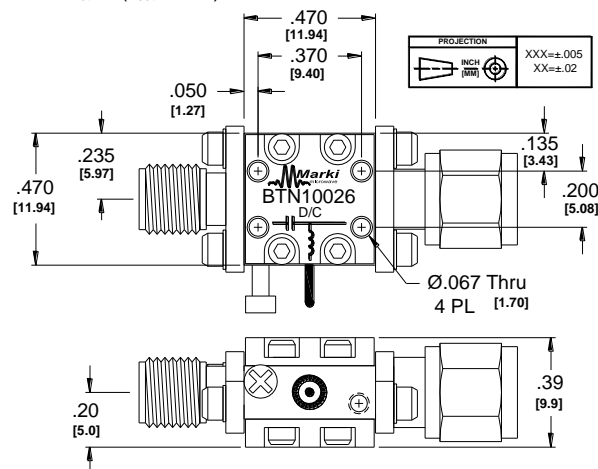
### Features

- Broadband: 500 kHz to 26.5 GHz
- Low Insertion Loss
- High Power
- Non-Resonant
- Compact Size

**Electrical Specifications** - Specifications guaranteed from -55 to +100°C, measured in a 50Ω system.

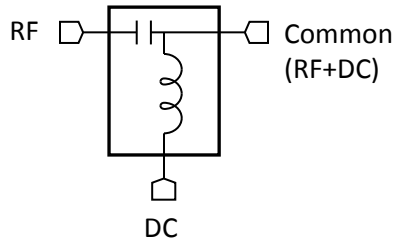
Parameter	Frequency Range	Min	Typ	Max
Insertion Loss (dB)	4 MHz-26.5 GHz		1	2
	500 kHz-4 MHz		2	
DC Port Isolation (dB)	500 kHz -1 GHz		50	
	1-26.5 GHz		30	
Return Loss (dB)	500 kHz-26.5 GHz		14	
RF Power (W)				10
DC Current (A)				1
DC Voltage (V)				50
DC Resistance (Ω)			0.5	
Risetime /Falltime (ps) <sup>1</sup>			10	

<sup>1</sup>Specified as 90%/10%. Calculated from  $\tau_{bt}^2 = (\tau_{out}^2 - \tau_{in}^2)$



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**Schematic**



**Application Examples**

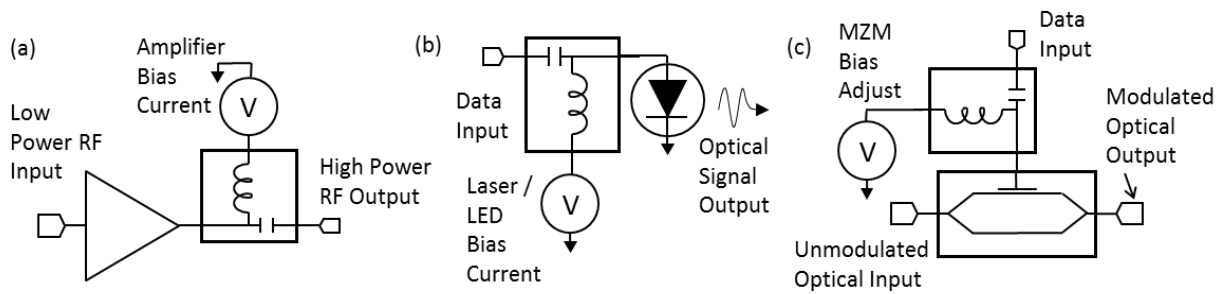


Fig. 1. Example Schematics of a) Broadband Microwave Amplifier Biasing, b) Laser/LED Biasing for Data Communication and c) Mach-Zender Modulator Biasing for Data Communication

**Typical Performance**

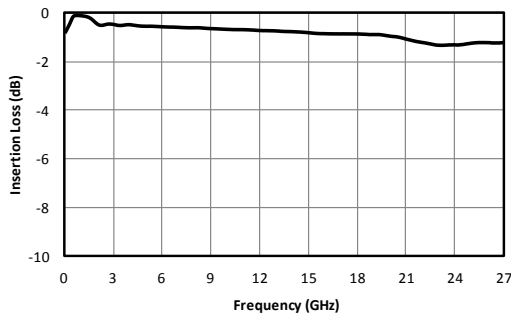


Fig. 2. RF insertion loss.

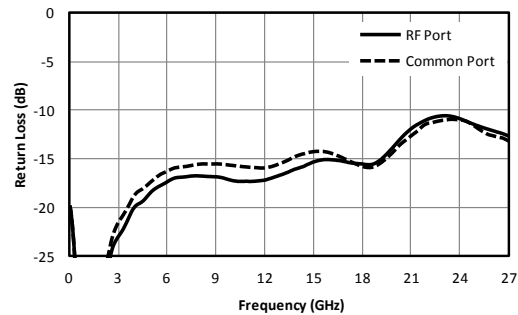


Fig. 3. Return loss.

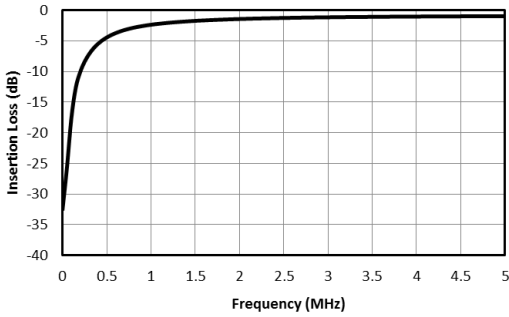


Fig. 4. Low frequency RF response.

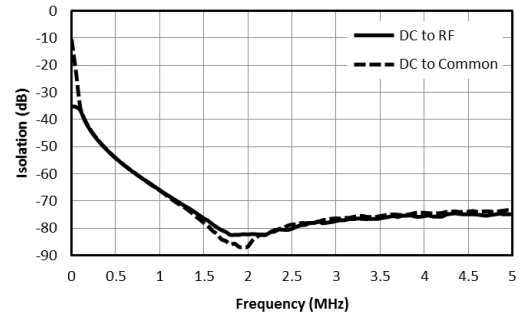


Fig. 5. Low frequency isolation.

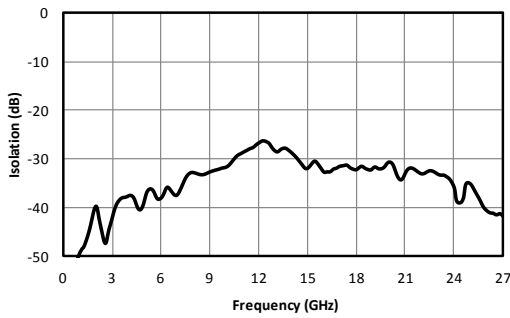


Fig. 6. DC-RF isolation.

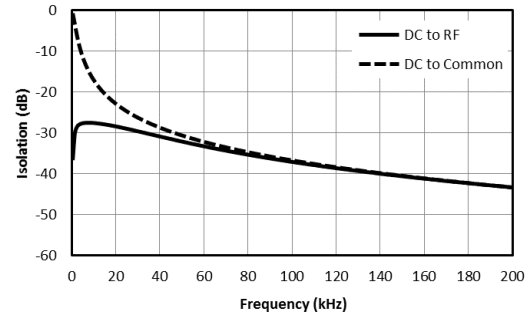


Fig. 7. Near DC isolation

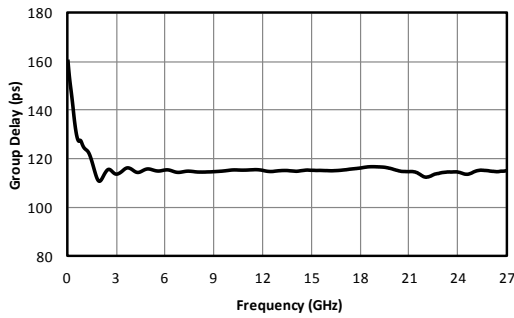


Fig. 8. Group delay.

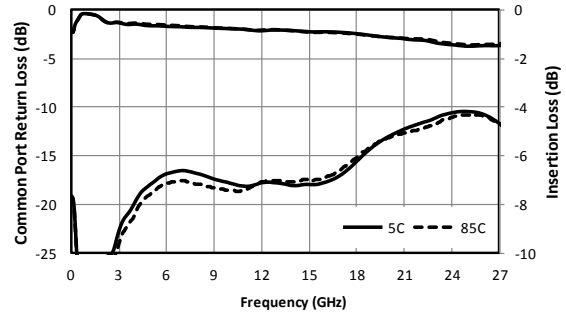


Fig. 9. Performance over temperature

**Typical Performance vs Bias Current at Low frequencies**

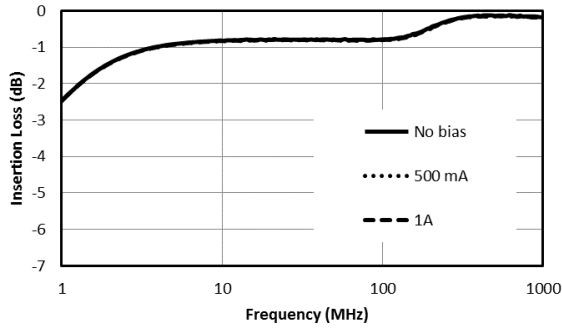


Fig. 10. Insertion Loss vs Bias Current.

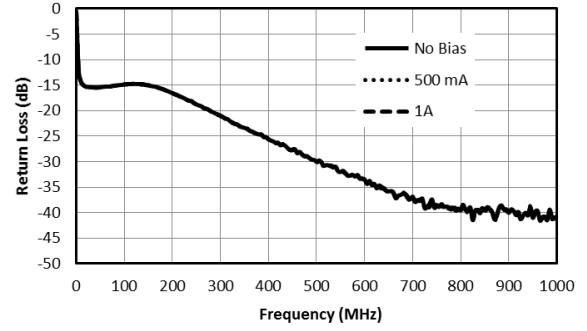


Fig. 11. Common Return Loss vs Bias Current.

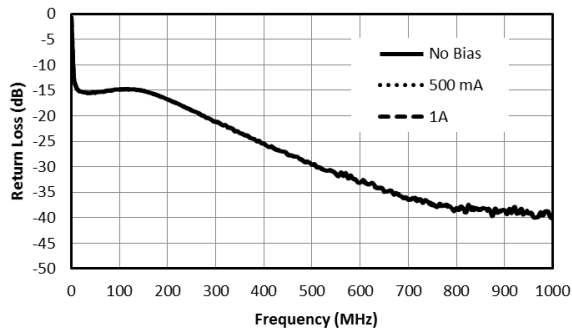


Fig. 12. RF Return Loss vs Bias Current.

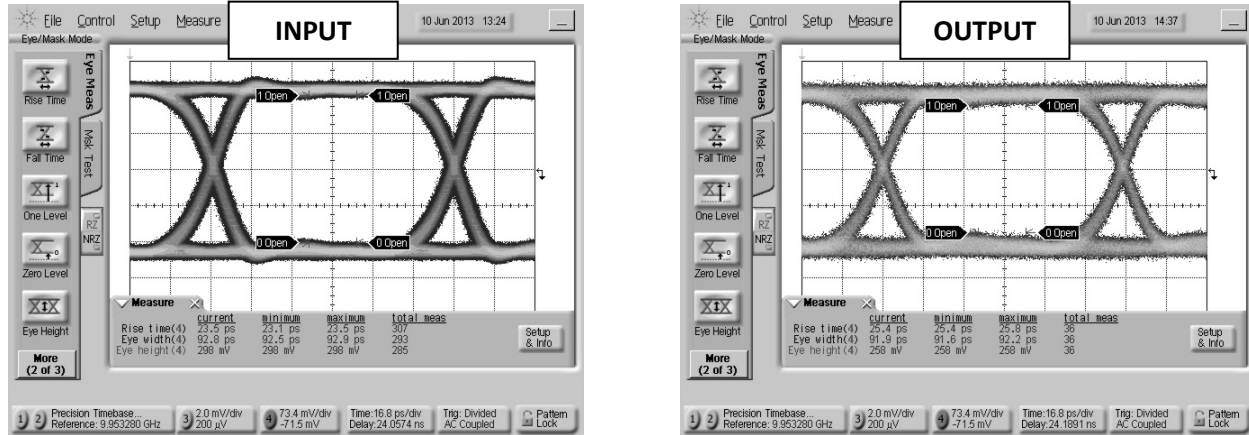


Fig. 13. Oscilloscope measurements of the BTN1-0026 with a 10Gb/s PRBS pattern. Eye diagrams are taken with a 2<sup>31</sup>-1 PRBS input demonstrating minimal eye distortion/closure afforded by the extremely low frequency operation of the bias tee.

Model Number	Description
BTN1-0026	500 kHz to 26.5 GHz High Power Bias Tee with SMA connectors <sup>1</sup>

<sup>1</sup>Consult factory for other connector options.

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**Revision History**

Revision code	Revision Date	Comment
-	June 2013	Datasheet initial Release
A	February 2019	Corrected Low Frequency plots
B	October 2020	RoHS Assembly